Product data sheet

1. General description

Standard reverse recovery power diode in a 2-lead TO220 package.





2. Features and benefits

- Low forward voltage drop
- Low leakage current
- High voltage capability
- · High inrush current capability

3. Applications

- · Input rectifier
- Bypass diode

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Values			Unit	
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage			80	00		V
$I_{F(AV)}$	average forward current	$δ = 0.5$; square-wave pulse; $T_{mb} \le 97$ °C; Fig. 1; Fig. 2; Fig. 3	35			А	
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4				А	
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse				А	
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static ch	aracteristics						
V _F	forward voltage	I _F = 20 A; T _j = 25 °C; <u>Fig. 6</u>		-	1.05	1.25	V
		I _F = 20 A; T _j = 150 °C; <u>Fig. 6</u>		-	1.00	1.20	V
		I _F = 35 A; T _j = 25 °C; <u>Fig. 6</u>		-	1.18	1.40	V
		I _F = 35 A; T _j = 150 °C; <u>Fig. 6</u>		-	1.15	1.35	V

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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode	mb	1/ 1/4 A
2	А	anode	}	K — A 001aaa020
mb	mb	mounting base; connected to cathode	O	

6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
WND35P08	TO220-2L	WND35P08Q	Tube	50	SOD59	27-Nov-2012

7. Marking

Table 4. Marking codes

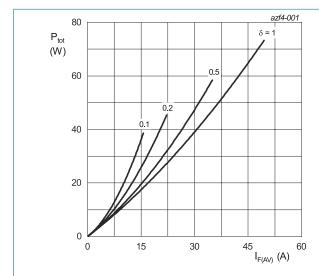
Type number	Marking codes
WND35P08	WND35P08

8. Limiting values

Table 5. Limiting values

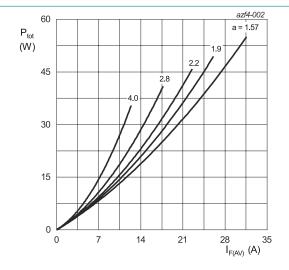
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{RRM}	repetitive peak reverse voltage		800	V
V_{RWM}	crest working reverse voltage		800	V
V_R	reverse voltage	DC	800	V
I _{F(AV)}	average forward current	$δ = 0.5$; square-wave pulse; $T_{mb} \le 97$ °C; Fig. 1; Fig. 2; Fig. 3	35	А
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	400	А
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	435	А
l ² t	I ² t for fusing	sine-wave pulse; $T_{j(init)} = 25 \text{ °C}$; $t_p = 10 \text{ ms}$	800	A ² s
T _{stg}	storage temperature		-40 to 150	°C
T _j	junction temperature		-40 to 150	°C



 $I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$ $V_o = 1.025 \text{ V}; R_s = 0.0092 \Omega$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



a = form factor = $I_{F(RMS)}/I_{F(AV)}$ $V_o = 1.025 \text{ V}; R_s = 0.0092 \Omega$

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

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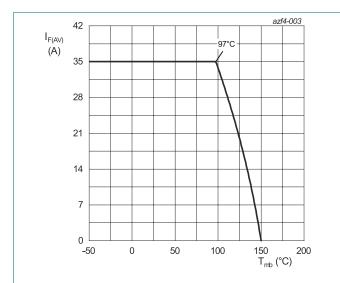


Fig. 3. Forward current as a function of mounting base temperature; maximum values

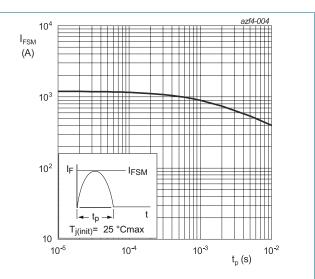


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

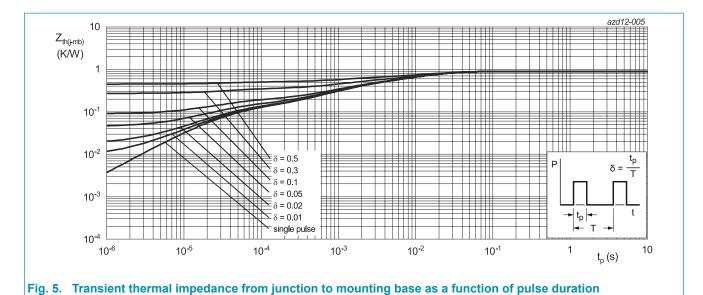
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9. Thermal characteristics

Table 6. Thermal characteristics

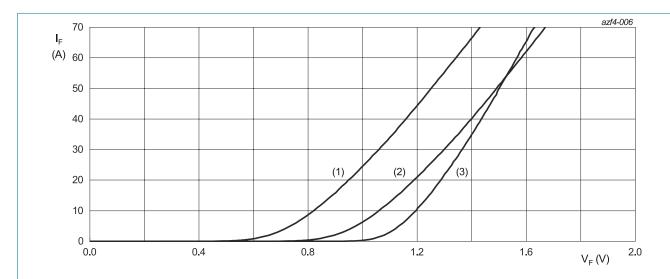
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 5	-	-	0.9	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	in free air	-	60	-	K/W



10. Characteristics

Table 7. Characteristics

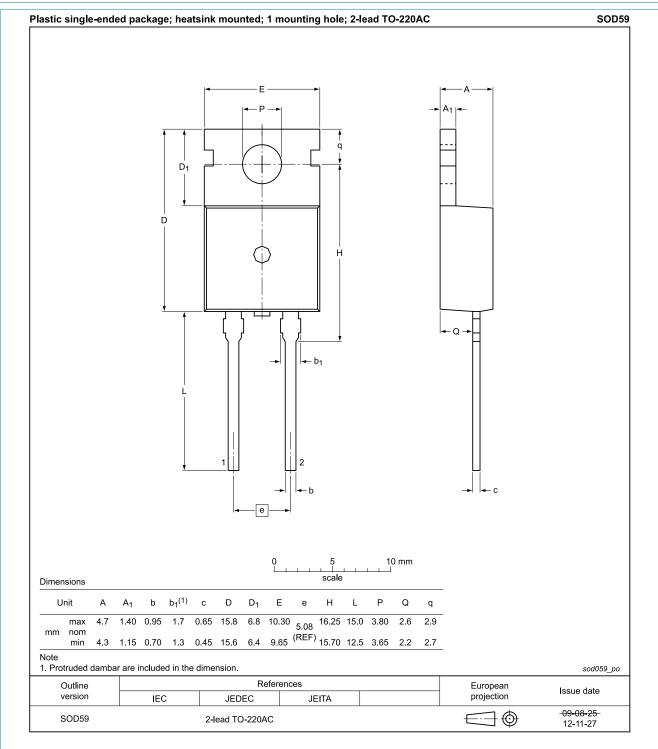
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
V _F	forward current	I _F = 20 A; T _j = 25 °C; <u>Fig. 6</u>	-	1.05	1.25	V
		I _F = 20 A; T _j = 150 °C; <u>Fig. 6</u>	-	1.00	1.20	V
		I _F = 35 A; T _j = 25 °C; <u>Fig. 6</u>	-	1.18	1.40	V
		I _F = 35 A; T _j = 150 °C; <u>Fig. 6</u>	-	1.15	1.35	V
I _R	reverse current	V _R = 800 V; T _j = 25 °C	-	-	50	μA
		V _R = 800 V; T _j = 150 °C	-	-	1	mA
		$V_R = 800 \text{ V}; I_j = 150 \text{ °C}$	-	-		1



 V_o = 1.025 V; R_s = 0.0092 Ω (1) T_j = 150 °C; typical values (2) T_j = 150 °C; maximum values (3) T_j = 25 °C; maximum values

Fig. 6. Forward current as a function of forward voltage

11. Package outline



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12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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- [2] The term 'short data sheet' is explained in section "Definitions".
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